# **Digital Transistors (BRT) R1 = 47 k** $\Omega$ , **R2 = 22 k** $\Omega$

NPN Transistors with Monolithic Bias Resistor Network

# MUN2237, MMUN2237L, MUN5237, DTC144WE, DTC144WM3, NSBC144WF3

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C) Rating Symbol Max Unit Collector-Base Voltage $V_{CBO}$ 50 Vdc Collector-Emitter Voltage VCEO 50 Vdc Collector Current - Continuous 100 $I_{C}$ mAdc Vdc Input Forward Voltage 40 VIN(fwd) V<sub>IN(rev)</sub> Input Reverse Voltage 10 Vdc

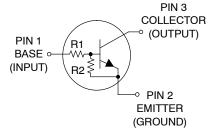
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

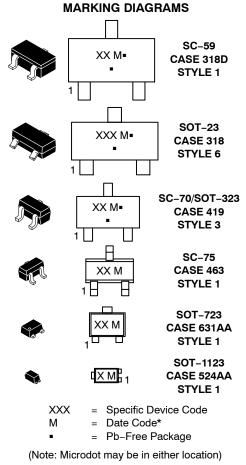


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#### PIN CONNECTIONS





\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

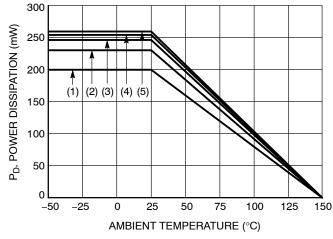
See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.

#### Table 1. ORDERING INFORMATION

Device	Part Marking	Package	Shipping <sup>†</sup>
MUN2237T1G, NSVMUN2237T1G*	8P	SC–59 (Pb–Free)	3000 / Tape & Reel
MMUN2237LT1G, NSVMMUN2237LT1G*	AA3	SOT-23 (Pb-Free)	3000 / Tape & Reel
MUN5237T1G, NSVMUN5237T1G*	8P	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel
DTC144WET1G, NSVDTC144WET1G*	8P	SC-75 (Pb-Free)	3000 / Tape & Reel
DTC144WM3T5G	8P	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSBC144WF3T5G	Q	SOT-1123 (Pb-Free)	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NSV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.



SC-75 and SC-70/SOT323; Minimum Pad
 SC-59; Minimum Pad
 SOT-23; Minimum Pad
 SOT-1123; 100 mm<sup>2</sup>, 1 oz. copper trace
 SOT-723; Minimum Pad

Figure 1. Derating Curve

#### **Table 2. THERMAL CHARACTERISTICS**

Characteristic		Symbol	Мах	Unit
THERMAL CHARACTERISTICS (SC-59) (MUN2237)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 1) (Note 2) (Note 1)	P <sub>D</sub>	230 338 1.8	mW mW/°C
Thermal Resistance,	(Note 2) (Note 1)	R <sub>θJA</sub>	2.7 540	°C/W
Junction to Ambient Thermal Resistance,	(Note 2) (Note 1)	$R_{ ext{ heta}JL}$	370 264	°C/W
Junction to Lead	(Note 2)		287	00
Junction and Storage Temperature Range THERMAL CHARACTERISTICS (SOT-23) (MMUN2237L)		T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C
Total Device Dissipation $T_A = 25^{\circ}C$	(Note 1)	P <sub>D</sub>	246	mW
Derate above 25°C	(Note 2) (Note 1) (Note 2)		400 2.0 3.2	mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	$R_{\thetaJA}$	508 311	°C/W
Thermal Resistance, Junction to Lead	(Note 1) (Note 2)	$R_{\theta JL}$	174 208	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5237)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	(Note 1) (Note 2) (Note 1) (Note 2)	P <sub>D</sub>	202 310 1.6 2.5	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	$R_{\thetaJA}$	618 403	°C/W
Thermal Resistance, Junction to Lead	(Note 1) (Note 2)	$R_{\thetaJL}$	280 332	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C
THERMAL CHARACTERISTICS (SC-75) (DTC144WE)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 1) (Note 2) (Note 1)	P <sub>D</sub>	200 300 1.6	mW mW/°C
Thermal Resistance,	(Note 2) (Note 1)	R <sub>θJA</sub>	2.4 600	°C/W
Junction to Ambient Junction and Storage Temperature Range	(Note 2)	T <sub>J</sub> , T <sub>stg</sub>	400 -55 to +150	°C
THERMAL CHARACTERISTICS (SOT-723) (DTC144WM3)		· J, 'SIG	10 10 1100	Ŭ
Total Device Dissipation $T_A = 25^{\circ}C$	(Note 1) (Note 2)	PD	260 600	mW
Derate above 25°C	(Note 2) (Note 1) (Note 2)		2.0 4.8	mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	$R_{\thetaJA}$	480 205	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

FR-4 @ 1.0 x 1.0 Inch Pad.
 FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
 FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

#### **Table 2. THERMAL CHARACTERISTICS**

Characteristic		Symbol	Мах	Unit
THERMAL CHARACTERISTICS (SOT-1123) (NSBC144WF3)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 3) (Note 4) (Note 3) (Note 4)	P <sub>D</sub>	254 297 2.0 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 3) (Note 4)	$R_{\thetaJA}$	493 421	°C/W
Thermal Resistance, Junction to Lead	(Note 3)	$R_{\theta JL}$	193	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

1. FR-4 @ Minimum Pad.

2. FR-4 @ 1.0 x 1.0 Inch Pad.

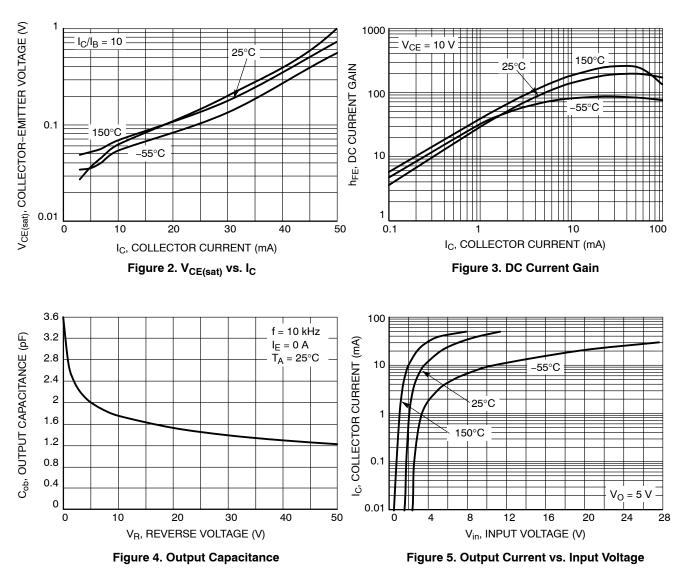
FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
 FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

#### Table 3. ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = $25^{\circ}$ C, unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		-	-		-
Collector-Base Cutoff Current $(V_{CB} = 50 \text{ V}, I_E = 0)$	Ісво	-	-	100	nAdc
Collector-Emitter Cutoff Current $(V_{CE} = 50 \text{ V}, I_B = 0)$	ICEO	-	_	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0 \text{ V}, I_C = 0$ )	I <sub>EBO</sub>	_	-	0.13	mAdc
Collector–Base Breakdown Voltage ( $I_C = 10 \ \mu A, I_E = 0$ )	V <sub>(BR)CBO</sub>	50	-	-	Vdc
Collector–Emitter Breakdown Voltage (Note 5) $(I_{C} = 2.0 \text{ mA}, I_{B} = 0)$	V <sub>(BR)CEO</sub>	50	-	-	Vdc
ON CHARACTERISTICS					
DC Current Gain (Note 5) ( $I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$ )	h <sub>FE</sub>	80	140	-	
Collector – Emitter Saturation Voltage (Note 5) ( $I_C = 10 \text{ mA}, I_B = 5.0 \text{ mA}$ )	VCE(sat)	_	-	0.25	Vdc
Input Voltage (off) $(V_{CE} = 5.0 \text{ V}, I_C = 100 \ \mu\text{A})$	V <sub>i(off)</sub>	_	1.8	1.2	Vdc
Input Voltage (on) ( $V_{CE} = 0.3 \text{ V}, I_C = 2.0 \text{ mA}$ )	V <sub>i(on)</sub>	4.0	2.3	-	Vdc
Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 4.0 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OL</sub>	_	-	0.2	Vdc
Output Voltage (off) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.25 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OH</sub>	4.9	-	-	Vdc
Input Resistor	R1	32.9	47	61.1	kΩ
Resistor Ratio	R <sub>1</sub> /R <sub>2</sub>	1.7	2.1	2.6	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product

performance may not be indicated by the Electrical Characteristics if operated under different conditions. 5. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq 2\%$ .



TYPICAL CHARACTERISTICS MUN2237, MMUN2237L, MUN5237, DTC144WE, DTC144WM3

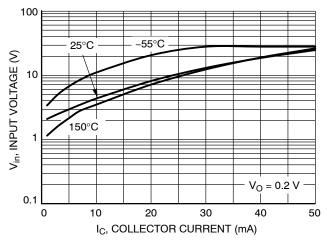
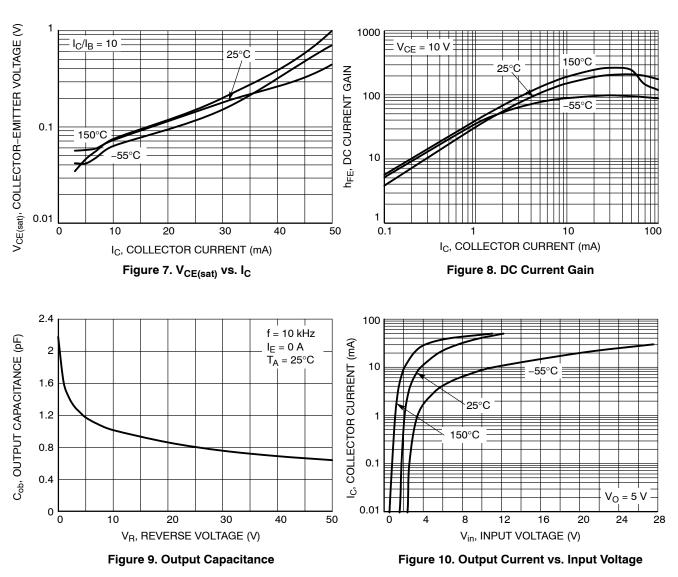
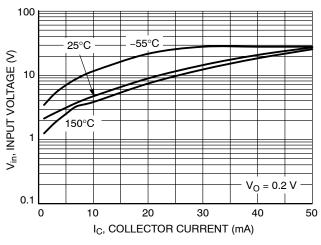


Figure 6. Input Voltage vs. Output Current



#### TYPICAL CHARACTERISTICS NSBC144WF3





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SCALE 2:1



#### **SOLDERING FOOTPRINT\***



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SC-59 CASE 318D-04 ISSUE H

DATE 28 JUN 2012

NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.00	1.15	1.30	0.039	0.045	0.051
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.35	0.43	0.50	0.014	0.017	0.020
С	0.09	0.14	0.18	0.003	0.005	0.007
D	2.70	2.90	3.10	0.106	0.114	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
е	1.70	1.90	2.10	0.067	0.075	0.083
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.80	3.00	0.099	0.110	0.118

#### GENERIC **MARKING DIAGRAM**



= Specific Device Code XXX Μ = Date Code

= Pb-Free Package\*

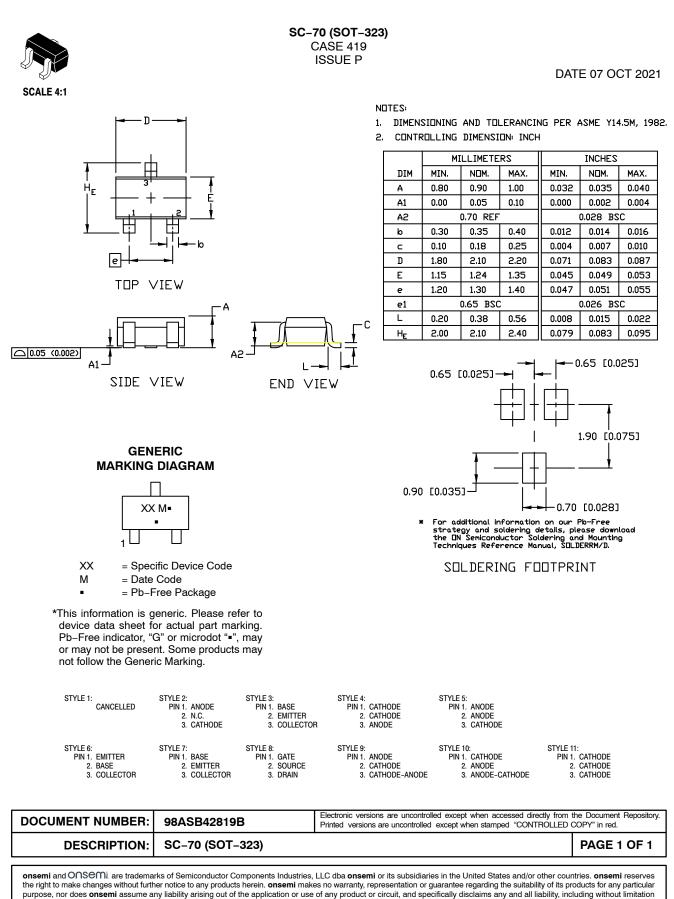
(\*Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present.

STYLE 1:	STYLE 2:	STYLE 3:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE
2. EMITTER	2. N.C.	2. ANODE
3. COLLECTOR	3. CATHODE	3. CATHODE
Style 4:	Style 5:	STYLE 6:
Pin 1. Cathode	Pin 1. Cathode	PIN 1. ANODE
2. n.C.	2. Cathode	2. CATHODE
3. Anode	3. Anode	3. ANODE/CATHODE

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1.000

0.039

SCALE 10:1

mm

inches

0.508

0.020

 
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SCALE 8:1



SOT-1123 CASE 524AA **ISSUE C** 





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STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. GATE
2. EMITTER	2. N/C	2. ANODE	2. CATHODE	2. SOURCE
3. COLLECTOR	3. CATHODE	3. CATHODE	3. ANODE	3. DRAIN

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- NOTES:
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- MINIMUM THICKNESS OF BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. 4.

	MILLIMETERS	
DIM	MIN	MAX
Α	0.34	0.40
b	0.15	0.28
b1	0.10	0.20
С	0.07	0.17
D	0.75	0.85
Е	0.55	0.65
е	0.35	0.40
HE	0.95	1.05
L	0.185 REF	
L2	0.05	0.15

GENERIC **MARKING DIAGRAM\*** 

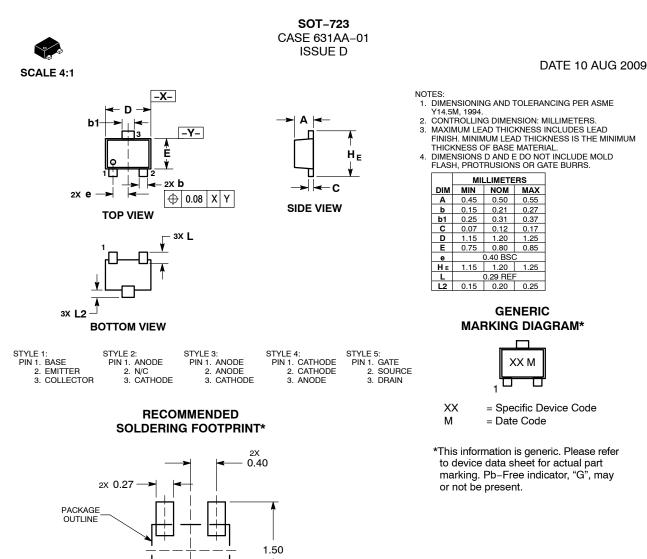
= Specific Device Code Х Μ = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " .", may or may not be present.

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3X 0.52 - - 0.36 DIMENSIONS: MILLIMETERS

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